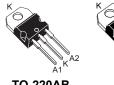


120 V power Schottky rectifier







TO-220AB narrow leads

Features

- · High junction temperature capability
- · Avalanche rated
- Low leakage current
- Good trade-off between leakage current and forward voltage drop
- ECOPACK®2 compliant

Applications

- · Switching diode
- SMPS
- DC/DC converter
- LED lighting
- Notebook adapter

Description

This dual center tap Schottky rectifier is ideally suited for high frequency switch mode power supply.

Packaged in TO-220AB and TO-220AB narrow leads, the STPS40120C is optimized for use in notebook and LCD adapters, desktop SMPS, providing in these applications a margin between the remaining voltages applied on the diode and the voltage capability of the diode.

Product status link		
STPS40120C		
Product summary		
Symbol Device		
I _{F(AV)} 2 x 20 A		
V _{RRM}	120 V	
T _j (max.) 175 °C		
V_F (typ.) 0.69 V		



Characteristics

Table 1. Absolute ratings (limiting values at 25 °C unless otherwise specified, per diode)

Symbol	Parameter			Unit
V _{RRM}	Repetitive peak reverse voltage	120	V	
I _{F(RMS)}	Forward rms current			Α
	Average forward current , T_c = 145 °C, δ = 0.5	Per diode	20	A
I _{F(AV)}		Per device	40	
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		200	Α
P _{ARM}	Repetitive peak avalanche power t_p = 10 μ s, T_j = 125 $^{\circ}$ C		755	W
T _{stg}	Storage temperature range			°C
Tj	Maximum operating junction temperature (1)			°C

^{1.} $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameters

Symbol	Parameter		Max. value	Unit
D.,	D. Junetien to eace	Per diode	1.6	
R _{th(j-c)} Junction to case	Total	0.85	°C/W	
R _{th(c)}	Coupling		0.1	

When the diodes 1 and 2 are used simultaneously:

 ΔT_j (diode 1) = P(diode 1) x $R_{th(j-c)}$ (per diode) + P(diode 2) x $R_{th(c)}$

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I_(1)	I _R ⁽¹⁾ Reverse leakage current	T _j = 25 °C	$V_R = V_{RRM}$	-		25	μA
IR ^(*)		T _j = 125 °C		-	4	12	mA
	V _F ⁽²⁾ Forward voltage drop	T _j = 25 °C	I _F = 7.5 A I _F = 20 A	-		0.73	
		T _j = 125 °C		-	0.57	0.61	
V (2)		T _j = 25 °C		-		0.90	.,
VF(=)		T _j = 125 °C		-	0.69	0.73	V
		T _j = 25 °C	L = 40 A	-		1.00	
		T _j = 125 °C	I _F = 40 A	-	0.83	0.88	

^{1.} Pulse test: $t_p = 5$ ms, $\delta < 2\%$

To evaluate the conduction losses, use the following equation:

$$P = 0.58 \times I_{F(AV)} + 0.0075 \times I_{F^{2}(RMS)}$$

For more information, please refer to the following application notes related to the power losses:

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^{2.} Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$



- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

1.1 Characteristics (curves)

Figure 1. Average forward power dissipation versus average forward current (per diode)

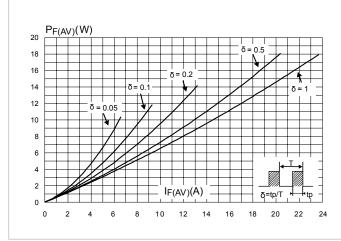


Figure 2. Average forward current versus ambient temperature (δ = 0.5, per diode)

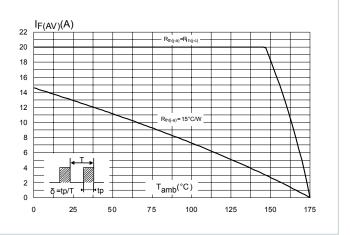


Figure 3. Normalized avalanche power derating versus pulse duration ($T_i = 125 \, ^{\circ}C$)

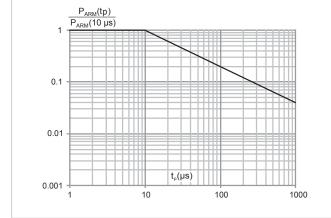
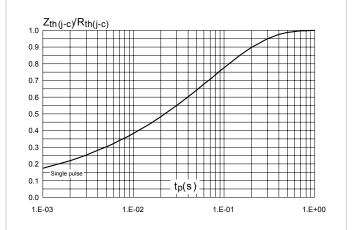


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration



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Figure 5. Reverse leakage current versus reverse voltage applied (typical values, per diode) I_R(mA) 1.E+02 1.E+01 ≣ T_i=150°C 1.E+00 T=100°C 1.E-02 1.E-03 1.E-04 1.E-05 90 0 20 30 100 110 10 40 50 60 70 80

Figure 6. Junction capacitance versus reverse voltage applied (typical values, per diode)

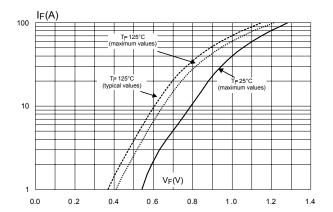
1000 C (pF)

1000 V_{R(V)}

10 V_{R(V)}

10 10 100

Figure 7. Forward voltage drop versus forward current (per diode)



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Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 TO-220AB package information

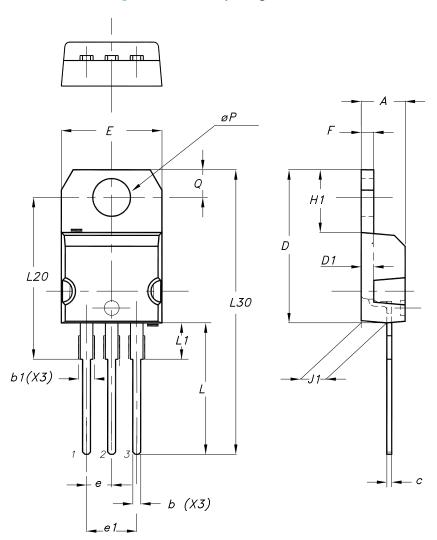
Epoxy meets UL 94,V0

Cooling method: by conduction (C)

Recommended torque value: 0.55 N·m

Maximum torque value: 0.70 N·m

Figure 8. TO-220AB package outline



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Table 4. TO-220AB package mechanical data

	Dimensions			
Ref.	Millimeters		Inches (for reference only)	
	Min.	Max.	Min.	Max.
А	4.40	4.60	0.173	0.181
b	0.61	0.88	0.240	0.035
b1	1.14	1.55	0.045	0.061
С	0.48	0.70	0.019	0.028
D	15.25	15.75	0.600	0.620
D1	1.2	7 typ.	0.050 typ.	
E	10.00	10.40	0.394	0.409
е	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
F	1.23	1.32	0.048	0.052
H1	6.20	6.60	0.244	0.260
J1	2.40	2.72	0.094	0.107
L	13.00	14.00	0.512	0.551
L1	3.50	3.93	0.138	0.155
L20	16.40 typ.		0.646 typ.	
L30	28.90 typ.		1.138 typ.	
θР	3.75	3.85	0.148	0.152
Q	2.65	2.95	0.104	0.116



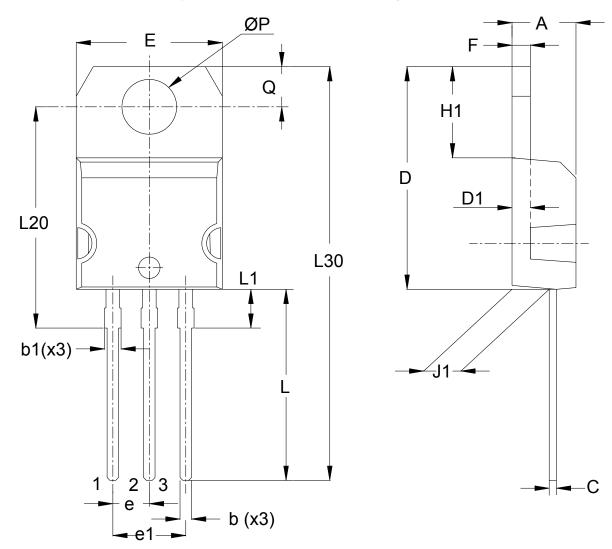
2.2 TO-220AB narrow leads package information

Epoxy meets UL94, V0

Cooling method: by conduction (C)
 Recommended torque value: 0.55 N·m

• Maximum torque value: 0.70 N·m

Figure 9. TO-220AB narrow leads package outline



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Table 5. TO-220AB narrow leads package mechanical data

	Dimensions				
Ref.	Millimeters		Inches (for reference only)		
	Min.	Max.	Min.	Max.	
Α	4.40	4.60	0.173	0.181	
b	0.61	0.88	0.240	0.035	
b1	0.95	1.20	0.037	0.047	
С	0.48	0.70	0.019	0.028	
D	15.25	15.75	0.600	0.620	
D1	1.2	77 typ.	0.050 typ.		
E	10.00	10.40	0.394	0.409	
е	2.40	2.70	0.094	0.106	
e1	4.95	5.15	0.195	0.203	
F	1.23	1.32	0.048	0.052	
H1	6.20	6.60	0.244	0.260	
J1	2.40	2.72	0.094	0.107	
L	13.00	14.00	0.512	0.551	
L1	2.60	2.90	0.138	0.155	
L20	15.40 typ.		0.646 typ.		
L30	28.90 typ.		1.138	typ.	
θР	3.75	3.85	0.148	0.152	
Q	2.65	2.95	0.104	0.116	

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3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS40120CT	STPS40120CT	TO-220AB	1.95 g	50	Tube
STPS40120CTN	PS40120CTN	TO-220AB narrow leads	1.9 g	50	Tube

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Revision history

Table 7. Document revision history

Date	Version	Changes
18-Feb-2005	1	First issue
1-Dec-2006	2	Reformatted to current standards. Added I ² PAK.
15-Sep-2011	3	Added TO-220AB narrow leads package.
21-Jun-2018	4	Removed I²PAK package, figure 4 and figure 5. Updated Figure 3. Normalized avalanche power derating versus pulse duration (T _j = 125 °C) and Table 1. Absolute ratings (limiting values at 25 °C unless otherwise specified, per diode). Minor text changes to improve readability.



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